Introduction

The MPC56xx family of devices have internal nonvolatile flash memory that is used for code and data. Two types of flash modules have been implemented on the Freescale MPC56xx devices, the C90FL and the C90LC. The C90FL flash is optimized for large flash memory arrays, while the C90LC is optimized for smaller flash array configurations. Flash memory is designed to allow fast programming, but requires that a full block be erased at a time. Once programmed, the flash memory retains its programmed state (nonvolatile) while powered off. In this technology, each cell in the flash memory array holds the value of one bit (either 0 for programmed or 1 for erased). This is a 2 level NOR flash implementation and uses a single voltage threshold to determine if a bit is high or low. This insures maximum data retention to meet harsh automotive requirements. For even more protection against bit-flips, this technology implements Error Correction Coding (ECC) that is guaranteed to correct single bit errors and will identify any double-bit errors within the ECC code word (64-bit data bits plus 8 ECC parity bits). Due to ECC, it is possible to put the flash memory into a state where the ECC bits are invalid. This can occur if an erase operation is interrupted prior to completion.
If a brownout occurs during an erase operation on the C90FL flash, the flash blocks being erased can be left in an indeterminate state (invalid ECC values). A brownout is defined as an accidental power loss or supply voltage drop or unexpected reset.

This application note describes how to recover the C90FL flash block(s) that were left in illegal states by an interrupted erase, if such a brownout occurs.

2 Devices affected

Devices that implement the C90FL flash module are shown in Table 1.

<table>
<thead>
<tr>
<th>Device</th>
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<tbody>
<tr>
<td>MPC564xA</td>
</tr>
<tr>
<td>MPC564xL</td>
</tr>
<tr>
<td>MPC564xS</td>
</tr>
<tr>
<td>MPC5668G/MPC5668F</td>
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<tr>
<td>MPC567xF</td>
</tr>
<tr>
<td>MPC5676R</td>
</tr>
</tbody>
</table>

3 C90FL flash memory erase operation

The C90FL flash memory erase operation consists of multiple steps that are implemented by the C90FL flash memory controller hardware.

1. **Program**: All bits in the selected flash memory block(s) are programmed to a threshold voltage (Vt) above the program verify level (P) to allow the erase operation to begin at a consistent state.
2. **Erase**: The erase step will erase all bits to a threshold voltage (Vt) that is below the erase verify level (E). Since erase is a bulk operation in which an erase pulse will move all the bits in a flash block, some of the bits will be over-erased, in other words, below compaction verify or soft program verify level.
3. **Compaction**: This step moves any bits that are over-erased up to reduce column leakage of the flash array.
4. **Soft Program**: At the soft program step, all the bits with a threshold voltage (Vt) below the soft program verify level will be programmed back with very low gate bias to avoid overshoot of erase verify level for any bits. As a result, when an erase operation is completed, all the bits in the selected blocks will have their threshold voltage within a predefined window between erase verify level (E) and soft program verify level (SP).

A flow diagram of these steps is shown in the figure below. In addition to the flow of the erase operation, this figure also includes a graphical representation of the threshold voltage of the flash bits in the cells. The graphs show the threshold voltage distribution of the flash bits after each operation in the flash cell by number of bits (#) versus the threshold voltage (V). It shows the relative values of:

- Program verify level (P)
- Soft program level (SP)
- Erase level (E)

**NOTE**

Erased bits (1) have a low threshold voltage and programmed bits (0) have a high threshold voltage.
4 Issue caused by brownout during flash memory erase

On C90FL flash memory, if an accidental power loss, supply voltage drop, or unexpected reset (that is, a brownout) occurs during a flash memory erase operation, the flash memory blocks being erased will most likely be left in an indeterminate state, depending on which step was executing when the erase operation was interrupted. If the flash memory block is in an indeterminate state, then the Error Correction Code for each flash word will not match the contents of the flash word. This will be seen as an uncorrectable error if the flash word is read by software.

Typically, to return the flash memory block(s) being interrupted back to a working state, users can simply perform an erase operation on the flash memory block(s). However, there are two cases that require special attention: recovering from non-correctable ECC errors and recovering from depleted bits.

4.1 Recover from non-correctable ECC errors

A brownout during a flash memory erase operation will very likely leave the bits in the block(s) being erased in a state such that when the block(s) are read, non-correctable ECC (error correcting code) errors will occur.
NOTE

In the C90FL flash memory, single-bit error correction and double-bit error detection (SEC-DED) ECC code is used.

For example, if the brownout occurs during the program step in the erase operation, many flash memory pages including the corresponding ECC bits will be left programmed. Note that all zeros is not a valid ECC codeword, and hence this will cause non-correctable ECC errors when reading those flash memory block(s). This can also be seen if the brownout occurs after the program step but in the middle of the erase step.

Even in this state, the flash memory block(s) can still be erased to recover. However, many flash programming tools, by default, may read flash memory while executing the erase code from RAM before performing an erase operation. As a result, an ECC error will be generated and hence an exception. If the flash programming tool does not have a proper exception handler implemented, the exception may cause code execution to hang. This will cause the erase operation to fail. The tool may include an option to not perform a read of a block prior to the erase operation\(^2\). See Example debugger erase script (Appendix A) for a sample debugger script that performs an erase operation without first performing a read of the flash memory.

To recover from such a state, users need to be aware of possible flash programmer tool failure for an erase operation caused by a flash ECC exception. Users can either use the FlashErase function provided in the MPC56xx C90FL flash standard software driver to erase the interrupted flash memory block(s), or use a Nexus/JTAG debugger script to simply toggle the low-level flash register bits to perform the erase operation. Please refer to Example debugger erase script (Appendix A) for a sample Lauterbach Trace32 script for erasing C90FL flash.

### 4.2 Recover from depleted bits

It is also possible that a brownout during the flash erase operation will leave the bits in the flash memory block(s) being erased in an over-erased or depleted state. For instance, if the brownout occurs after the erase step, but prior to the compaction and soft program steps are completed, it is possible that the flash bits will be left in a depleted state (very low threshold voltage).

Depending on how depleted the bits are, excessive column leakage caused by the bits may cause the following program operation to fail due to suppressed drain bias. In other words, there would be insufficient voltage to allow the bit to be programmed. Note that the first step in an erase operation is a program step, and thus for this case, the erase operation to recover the interrupted flash memory block(s) might fail. It will appear to users that the flash memory block(s) cannot be erased and recovered.

In this case, to recover the depleted flash memory block(s), users first need to use the binary C-array FlashDepletionRecover function provided in the MPC56xx C90FL flash standard software driver to recover the depleted bits in the flash memory block(s). Then the erase operation must be restarted to recover the block(s). The FlashDepletionRecover function in the flash driver is called in a similar way as any of the other binary C-array flash driver functions. Please refer to Example depletion recovery code (Appendix B) for example code for calling this function to recover depleted blocks.

For EEPROM emulation applications, this case is handled in the MPC56xx C90FL EEPROM emulation software driver provided by Freescale. Basically, there is brownout handling code in the FSL_InitEeprom function. If an erase operation fails to recover the interrupted flash memory block(s), a call to FlashDepletionRecover function will be made to recover the depleted bits, and then an erase operation will be started again to recover the interrupted flash memory block(s).

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2. Check with your flash programming tool provider for instructions to disable reads prior to an erase.
5 Conclusion

Typically, if an erase operation is interrupted due to a brownout, simply repeating the flash erase operation will recover the flash memory block(s). However, special care needs to be considered for cases in which an erase operation does not remove ECC errors and depleted bits. A generic erase should always be used initially. If the generic erase fails, the new FlashDepletionRecover function should be used to fix non-correctable ECC errors and bits left in a depleted state.

6 Revision history

Table 2. Revision history

<table>
<thead>
<tr>
<th>Revision number</th>
<th>Date</th>
<th>Description of changes</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>02 May 2012</td>
<td>Substantially expanded information throughout document and added images. (Revision 0 not publicly released.)</td>
</tr>
</tbody>
</table>

Appendix A Example debugger erase script

Here is an example script (erase_blk.cmm) that will restore a C90FL flash to a standard erased state. This is essentially the same as the FlashErase() function of the MPC56xx C90FL flash standard software driver. This example is written for the MPC564xL using the Lauterbach Trace32 debugger. The script is called with the values of the Low/Mid-Address Select register value and the high-address select register value in the following manner to erase the Low Address Space block 0 (LAS0):

do erase_blk.cmm 1 0

Here is a listing of the erase_blk.cmm script file

`;lblk and hblk are inputs (corresponding to the Low/Mid-address space block
;and high-address select registers) to select which block(s) to be erased
entry &lblk &hblk &mcr &fdone

;reset MCR
data.set ea:0xc3f88000 %long 0

;enable block
data.set ea:0xc3f88010 %long &lblk
data.set ea:0xc3f88014 %long &hblk
&fdone=0

;set ERS
data.set ea:0xc3f88000 %long 0x4

;interlock write
data.set ea:0x00000000 %long 0xffffffff

;set EHV
data.set ea:0xc3f88000 %long 0x5

;wait for DONE
while &fdone==0
{
Appendix B Example depletion recovery code

This listing is an example of calling the FlashDepletionRecover function from the MPC56xx C90FL flash standard software driver to recover depleted blocks of the flash memory.

```c
#include    "ssd_types.h"
#include    "ssd_c90fl.h"
#include    "normaldemo.h"

extern const unsigned int FlashInit_C[];
extern const unsigned int FlashDepletionRecover_C[];
extern const unsigned int SetLock_C[];

/* Assign function pointers */
pFLASHINIT pFlashInit = (pFLASHINIT) FlashInit_C;
pSETLOCK pSetLock = (pSETLOCK) SetLock_C;
pFLASHDEPLETIONRECOVER pFlashDepletionRecover = (pFLASHDEPLETIONRECOVER) FlashDepletionRecover_C;

SSD_CONFIG ssdConfig = {
    C90FL_REG_BASE,         /* c90fl control register base */
    MAIN_ARRAY_BASE,        /* base of main array */
    0,                      /* size of main array */
    SHADOW_ROW_BASE,        /* base of shadow row */
    SHADOW_ROW_SIZE,        /* size of shadow row */
    0,                      /* block number in low address space */
    0,                      /* block number in middle address space */
    0,                      /* block number in high address space */
    0x10,                   /* page size */
    FALSE                   /* debug mode selection */
};

UINT32 main(void)
{
    UINT32 returnCode;           /* Return code from each SSD function. */
    BOOL shadowFlag;             /* shadow select flag */
    UINT32 lowEnabledBlocks;     /* selected blocks in low space */
    UINT32 midEnabledBlocks;     /* selected blocks in middle space */
    UINT32 highEnabledBlocks;    /* selected blocks in high space */

    /*========================= Initialize Part =========================*/
    returnCode = pFlashInit( ssdConfig );
    if ( C90FL_OK != returnCode )
    {
        ErrorTrap(returnCode);
    }

    /* Unlock all main array blocks */
```
returnCode = pSetLock( &ssdConfig, LOCK_LOW_PRIMARY, 0, FLASH_LMLR_PASSWORD);
if ( C90FL_OK != returnCode )
{
    ErrorTrap(returnCode);
}
returnCode = pSetLock( &ssdConfig, LOCK_LOW_SECONDARY, 0, FLASH_SLMLR_PASSWORD);
if ( C90FL_OK != returnCode )
{
    ErrorTrap(returnCode);
}
returnCode = pSetLock( &ssdConfig, LOCK_MID_PRIMARY, 0, FLASH_LMLR_PASSWORD);
if ( C90FL_OK != returnCode )
{
    ErrorTrap(returnCode);
}
returnCode = pSetLock( &ssdConfig, LOCK_MID_SECONDARY, 0, FLASH_SLMLR_PASSWORD);
if ( C90FL_OK != returnCode )
{
    ErrorTrap(returnCode);
}
returnCode = pSetLock( &ssdConfig, LOCK_HIGH, 0, FLASH_HLR_PASSWORD);
if ( C90FL_OK != returnCode )
{
    ErrorTrap(returnCode);
}

/**===== Deletion recover main array space ===================*/
shadowFlag = FALSE;
/* Select the all main array blocks */
lowEnabledBlocks = 0xffffffff;
midEnabledBlocks = 0xffffffff;
highEnabledBlocks = 0xffffffff;

returnCode = pFlashDepletionRecover( &ssdConfig, shadowFlag, lowEnabledBlocks,
midEnabledBlocks, highEnabledBlocks, NULL_CALLBACK );
if ( C90FL_OK != returnCode )
{
    ErrorTrap(returnCode);
}

/**************** DEMO FINISHED **************************/
return ((UINT32)DEMO_PASS);

******************************************************************************
<table>
<thead>
<tr>
<th>function implementations (scope: module-local)</th>
</tr>
</thead>
</table>
| /* Error trap function */
| void ErrorTrap(UINT32 returnCode) |
| { VUINT32 failedReason; |
|   failedReason = returnCode; |
|   while(1) |
|   { ; |
| } |
| } |

The function pointers for the driver functions are defined in “ssd_c90fl.h” as below:

typedef UINT32 (*pFLASHINIT) ( PSSD_CONFIG pSSDConfig );
typedef UINT32 (*pFLASHDEPLETIONRECOVER) ( |
PSSD_CONFIG pSSDConfig, |
BOOL shadowFlag, |
UINT32 lowEnabledBlocks, |
UINT32 midEnabledBlocks, |
... |
```c
UINT32 highEnabledBlocks,
void (*CallBack)(void)
);

typedef UINT32 (*pSETLOCK) (
    PSSD_CONFIG pSSDConfig,
    UINT8 blkLockIndicator,
    UINT32 blkLockState,
    UINT32 password
);
```

## Appendix C References

These documents, including each device's reference manual and data sheet, should also be referred to when working with the flash modules. All are available at www.freescale.com.

<table>
<thead>
<tr>
<th>Reference documents</th>
<th>Description</th>
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<tbody>
<tr>
<td>MPCxxxxRM</td>
<td>Device reference manual</td>
</tr>
<tr>
<td>MPCxxxxx</td>
<td>Device data sheet</td>
</tr>
<tr>
<td>User manual¹</td>
<td>MPC56xx C90FL Flash Standard Software Driver for Single Module Flash (version 1.0.0 or later)</td>
</tr>
<tr>
<td>User manual¹</td>
<td>MPC5674F_5676R_C90FL Flash Standard Software Driver (version 1.0.0 or later)</td>
</tr>
<tr>
<td>User manual¹</td>
<td>MPC56xx C90FL EEPROM Emulation Software Driver (version 1.0.1 or later)</td>
</tr>
<tr>
<td>AN4365</td>
<td>&quot;Qorivva MPC56xx Flash Programming Through Nexus/JTAG&quot;</td>
</tr>
<tr>
<td>EB618</td>
<td>&quot;Typical Data Retention for Nonvolatile Memory&quot;</td>
</tr>
<tr>
<td>EB619</td>
<td>&quot;Typical Endurance for Nonvolatile Memory&quot;</td>
</tr>
</tbody>
</table>

1. The user manual is installed in the directory with the flash driver and example code when the software driver is installed.
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